

LLC Resonant Converter $V_o=50V$ $I_o=50A$

LLC Resonant Converter Simulation Circuit

Input: $V_{in}=300V \sim 500V$

Output: $V_o=50V$ $I_{out}=10A \sim 50A$

PFM: $f_{sw}=50kHz \sim 100kHz$

Gate Drive: $V_d=10V$ / $V_s=-5V$
 $td1, td2=50ns$
 $R_g \text{ source}=5\Omega$
 $R_g \text{ sink}=2\Omega$

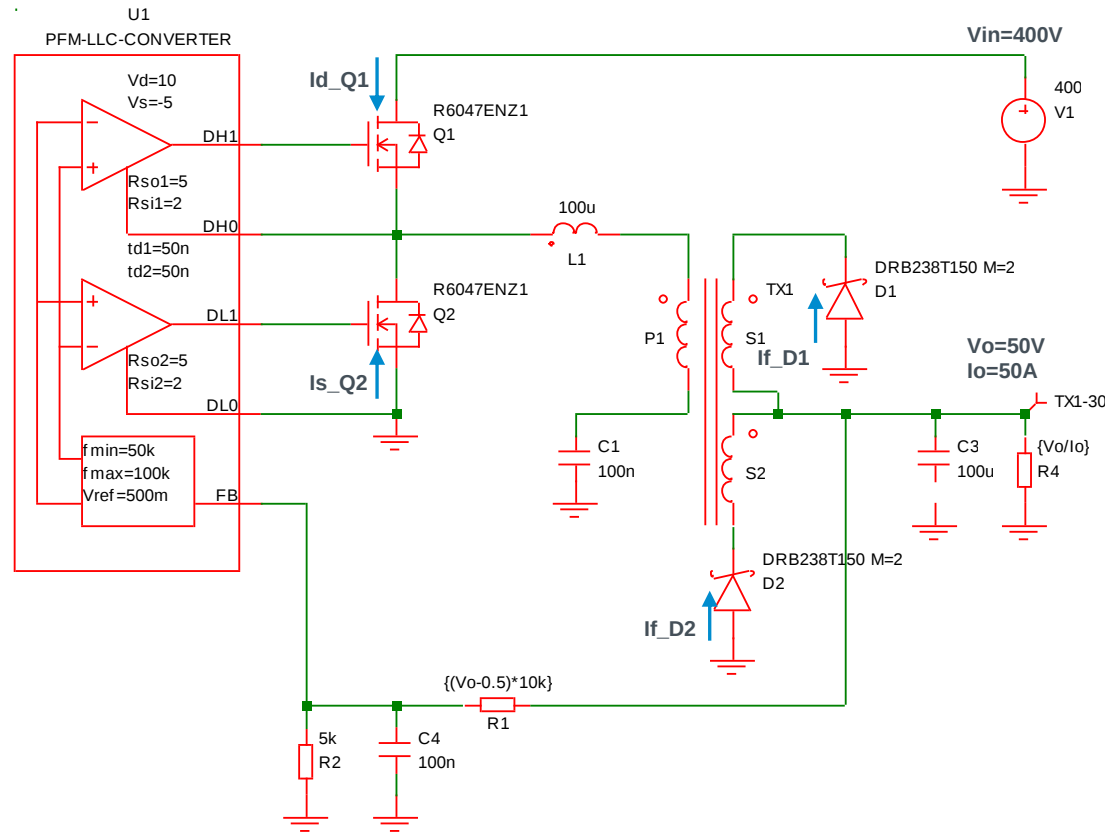
Q1,2: R6047ENZ1 MOSFET (600V 47A)
D1,2: RB238T150 SBD (150V 40A)

TX1: $500\mu H : 80\mu H + 80\mu H$ $K=1$

L1: $100\mu H$

C1: $100nF$

$T_j: -25^\circ C \sim 125^\circ C$



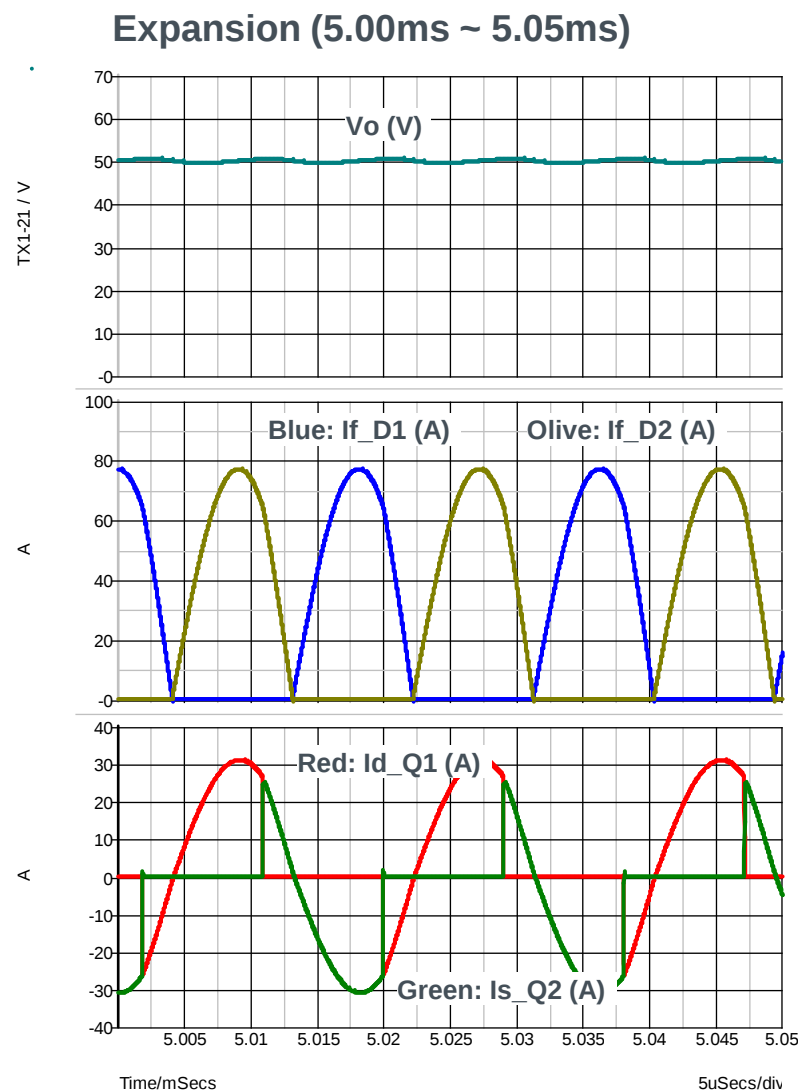
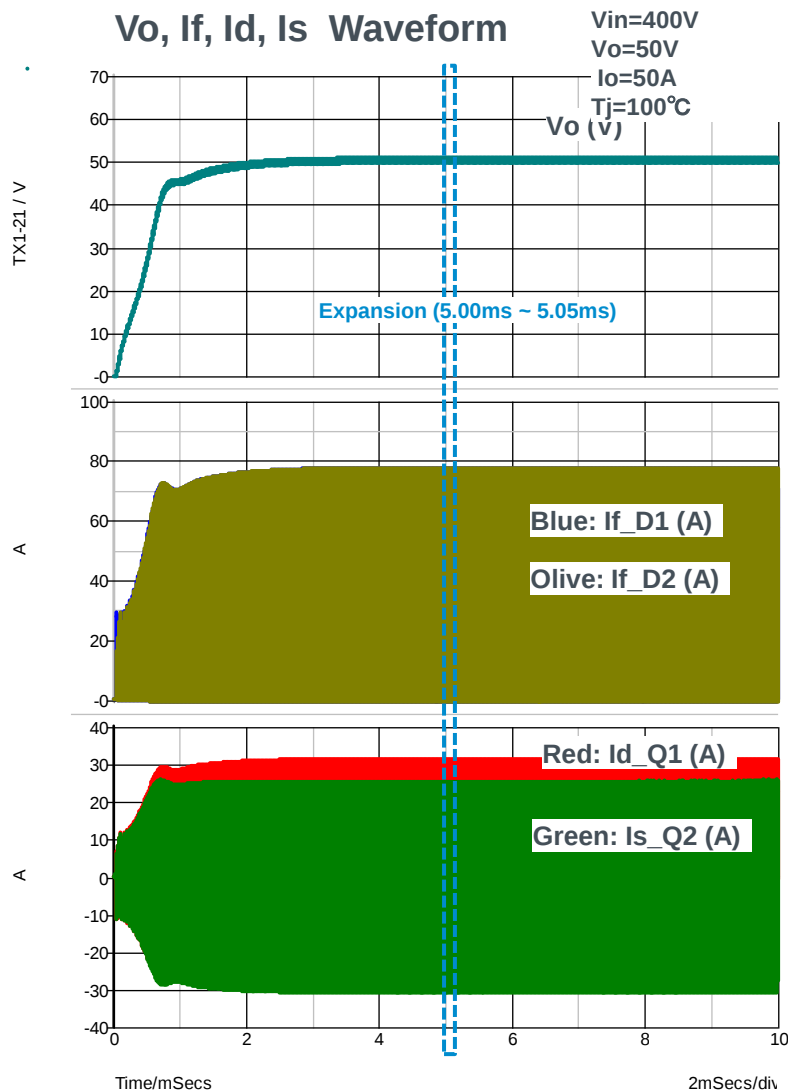
SIMetrix SPICE Simulation Data File



DC-DC LLC Resonant Converter $V_o=50V$ $I_o=50A.sxsch$

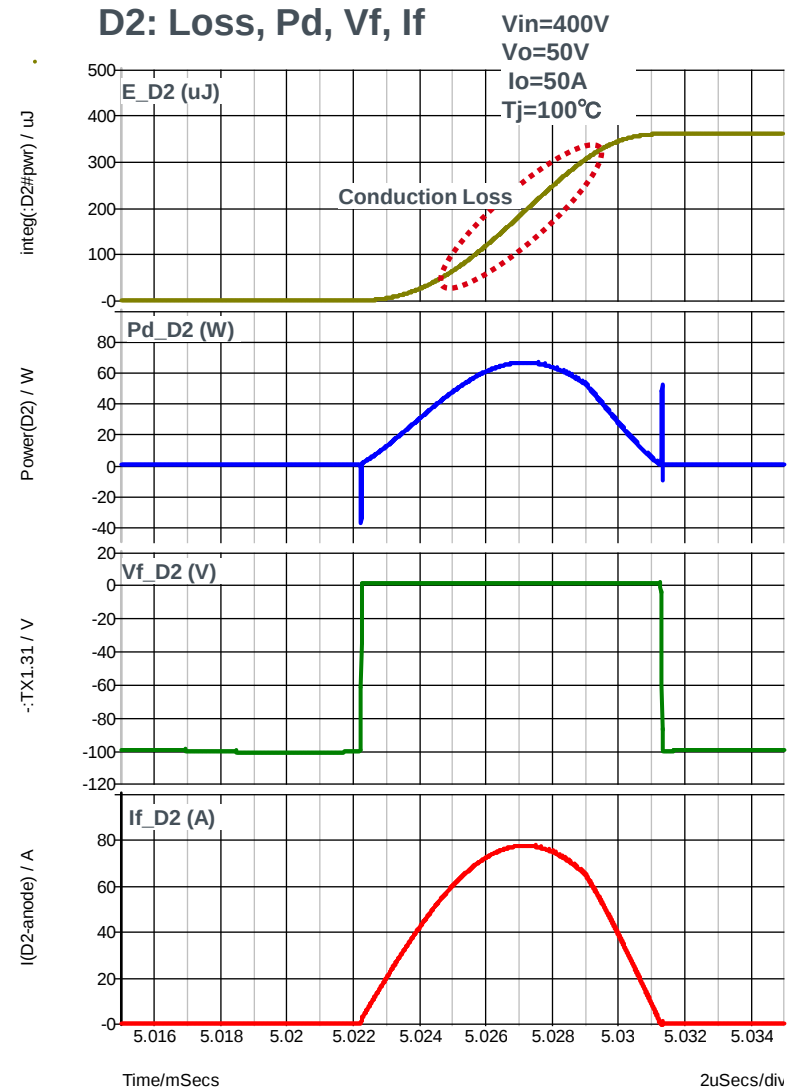
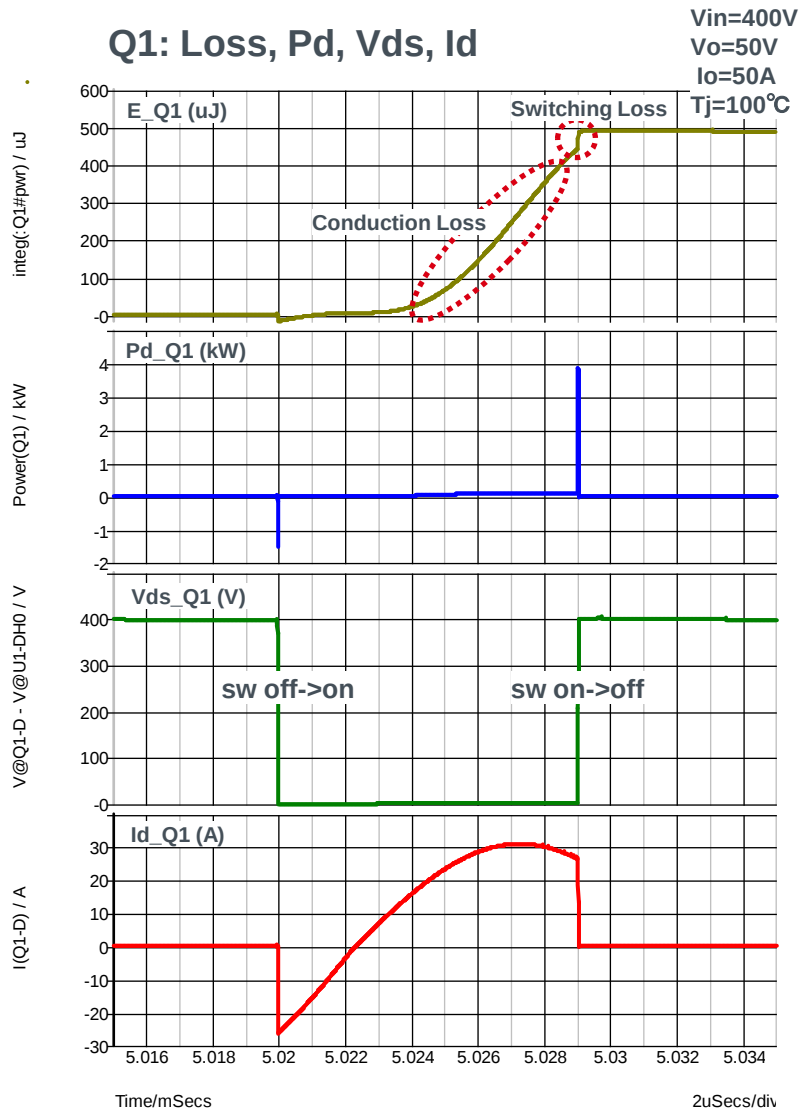
Simulation Waveform 1

ROHM PD SimG



Simulation Waveform 2

ROHM PD SimG

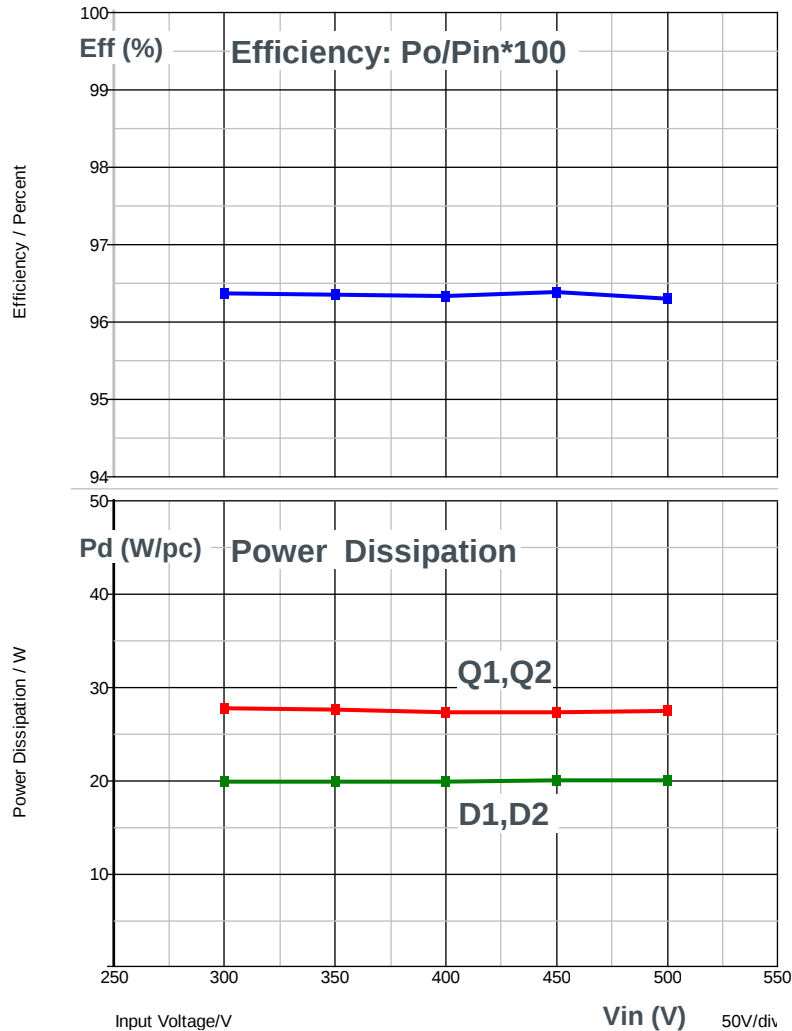


Efficiency, Power Dissipation 1

ROHM PD SimG

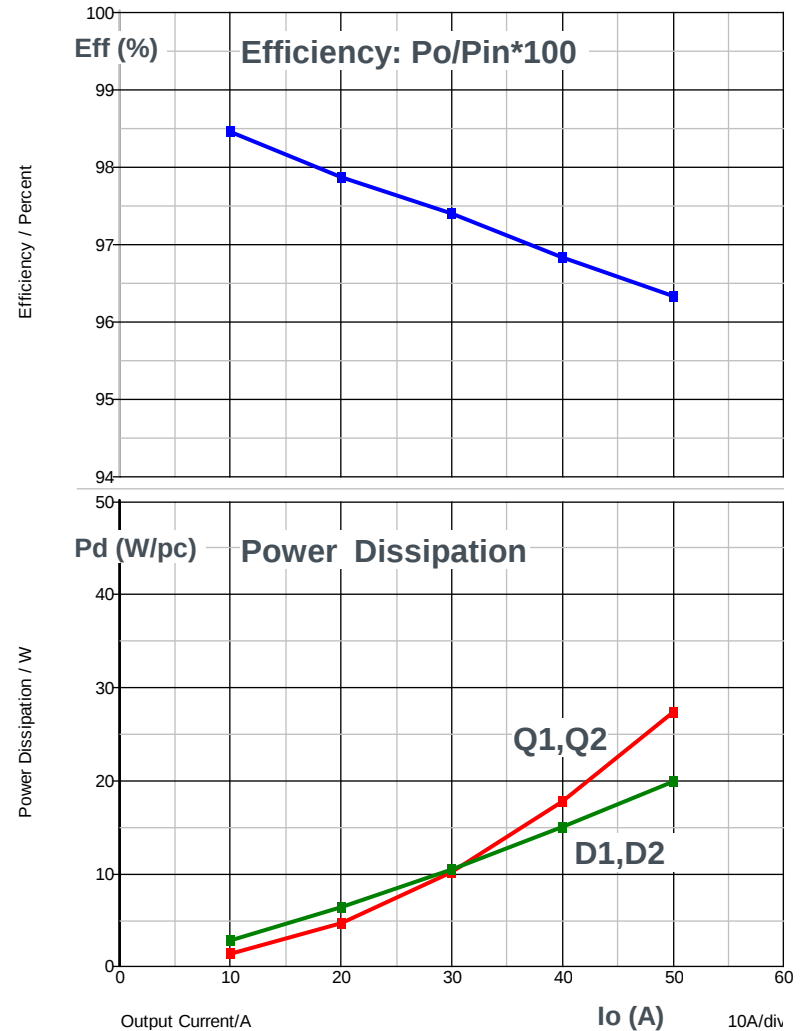
Vin: 300V ~ 500V

Vo=50V Io=50A
Tj=100°C



Io: 10A ~ 50A

Vin=400V Vo=50V
Tj=100°C



Efficiency, Power Dissipation 2

